

BC806 series

80 V, 500 mA PNP general-purpose transistors

Rev. 2 — 5 November 2019

Product data sheet

1. General description

PNP general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package		NPN complement:
	Nexperia	JEDEC	
BC806-16	SOT23	TO-236AB	BC816-16
BC806-25	SOT23	TO-236AB	BC816-25

2. Features and benefits

- High current
- · High voltage
- · Two current gain selections
- AEC-Q101 qualified

3. Applications

- · General-purpose switching and amplification
- · 48 V automotive board net

4. Quick reference data

Table 2. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base		-	-	-80	V
I _C	collector current			-	-	-500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	-1	А
h _{FE}	DC current gain						
	BC806-16	V _{CE} = -1 V; I _C = -100 mA	[1]	100	-	250	
	BC806-25		[1]	160	-	400	

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$



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5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base]3	С
2	Е	emitter		В
3	С	collector		, h
			1 2	E 006aaa231
			TO-236AB (SOT23)	

6. Ordering information

Table 4. Ordering information

Type number	Type number Package				
	Name	Description	Version		
BC806-16	TO-236AB	plastic, surface-mounted package; 3 leads	SOT23		
BC806-25	1				

7. Marking

Table 5. Marking

Type number	Marking code [1]
BC806-16	%GR
BC806-25	%GS

[1] % = placeholder for manufacturing site code

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8. Limiting values

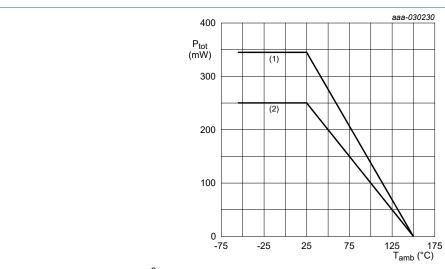
Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-80	V
V _{CEO}	collector-emitter voltage	open base		-	-80	V
V _{EBO}	emitter-base voltage	open collector		-	-8	V
I _C	collector current			-	-500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-1	Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	250	mW
			[2]	-	345	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm².



- (1) FR4 PCB; 1 cm² mounting pad for collector
- (2) FR4 PCB; standard footprint

Fig. 1. Power derating curves for SOT23

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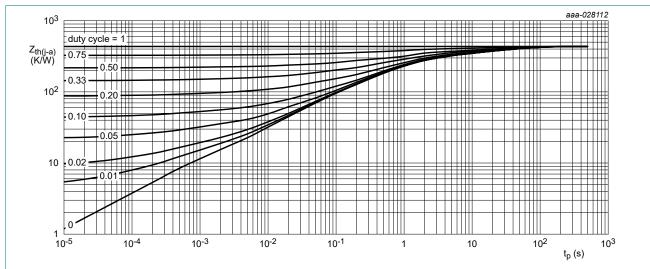
9. Thermal characteristics

Table 7. Thermal characteristics

 T_{amb} = 25 °C unless otherwise specified.

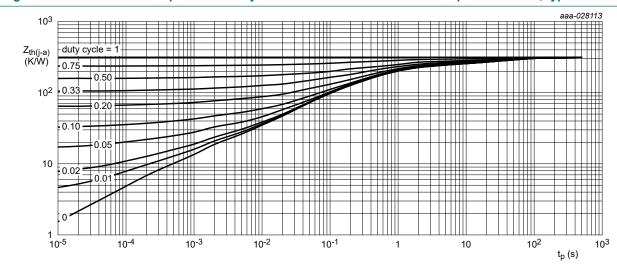
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W
			[2]	-	-	363	K/W

- 1] Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm².



FR4 PCB; single-sided copper; tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm²

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

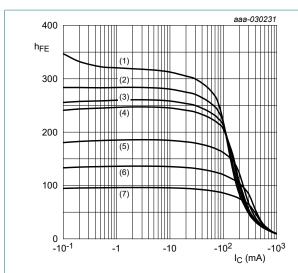
Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
$V_{(BR)CBO}$	collector-base breakdown voltage	I _C = -100 μA; I _E = 0 A		-80	-		V	
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = -2 mA; I _E = 0 A		-80	-		V	
$V_{(BR)EBO}$	emitter-base breakdown voltage	I _E = -100 μA; I _C = 0 A		-8	-		V	
I _{СВО}	collector-base	V _{CB} = -64 V; I _E = 0 A		-	-	-100	nA	
	cut-off current	V _{CB} = -64 V; I _E = 0 A; T _j = 150 °C		-	-	-5	μA	
I _{EBO}	emitter-base cut-off current	V _{EB} = -6.4 V; I _C = 0 A		-	-	-100	nA	
h _{FE}	DC current gain							
	BC806-16	V _{CE} = -1 V; I _C = -100 mA	[1]	100	-	250		
	BC806-25	V _{CE} = -1 V; I _C = -100 mA	[1]	160	-	400		
		V _{CE} = -2 V; I _C = -500 mA	[1]	30	-	-		
V _{CEsat}	collector-emitter	I _C = -100 mA; I _B = -10 mA	[1]	-	-	-150	mV	
	saturation voltage	I _C = -500 mA; I _B = -50 mA	[1]	-	-	-400	mV	
V _{BE}	base-emitter voltage	V _{CE} = -1 V; I _C = -500 mA	[1]	-	-	-1.2	V	
f _T	transition frequency	V _{CE} = -5 V; I _C = -50 mA; f = 100 MHz		80	-	-	MHz	
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	5	-	pF	

^[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$

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$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(3)
$$T_{amb}$$
 = 100 °C

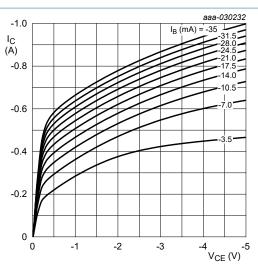
(4)
$$T_{amb} = 85 \, ^{\circ}C$$

(5)
$$T_{amb} = 25 \, ^{\circ}C$$

(6)
$$T_{amb} = -40 \, ^{\circ}C$$

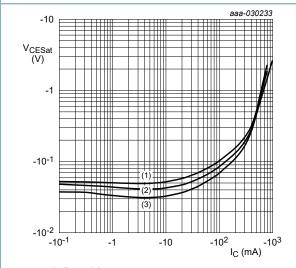
$$(7) T_{amb} = -55 °C$$





 $T_{amb} = 25 \, ^{\circ}C$

Fig. 5. BC806-16: Collector current as a function of collector-emitter voltage; typical values



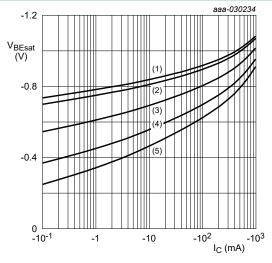
$$I_{\rm C}/I_{\rm B}=20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 6. BC806-16: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = -40 \, ^{\circ}C$$

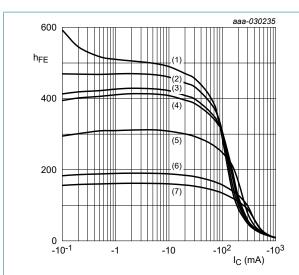
(3)
$$T_{amb} = 25 \, ^{\circ}C$$

(4)
$$T_{amb} = 100 \, ^{\circ}C$$

(5)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 7. BC806-16: Base-emitter saturation voltage as a function of collector current; typical values

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$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

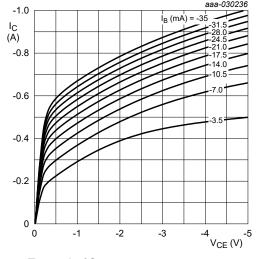
(3)
$$T_{amb}$$
 = 100 °C

(4)
$$T_{amb} = 85 \, ^{\circ}C$$

(5)
$$T_{amb} = 25 \, ^{\circ}C$$

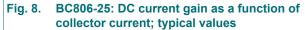
(6)
$$T_{amb} = -40 \, ^{\circ}C$$

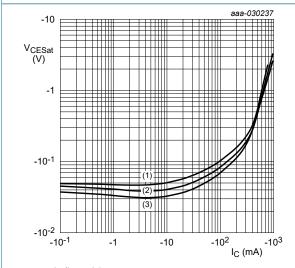
(7)
$$T_{amb} = -55 \, ^{\circ}C$$



 $T_{amb} = 25 \, ^{\circ}C$

Fig. 9. BC806-25: Collector current as a function of collector-emitter voltage; typical values





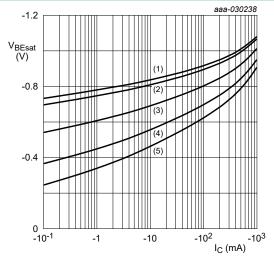
$$I_{\rm C}/I_{\rm B}=20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 10. BC806-25: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = -40 \, ^{\circ}C$$

(3)
$$T_{amb}$$
 = 25 °C

(4)
$$T_{amb} = 100 \, ^{\circ}C$$

(5)
$$T_{amb} = 150 \, ^{\circ}C$$

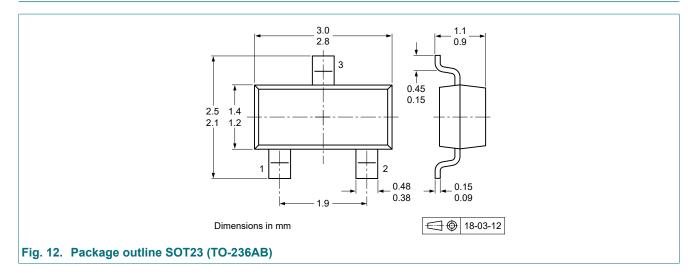
Fig. 11. BC806-25: Base-emitter saturation voltage as a function of collector current; typical values

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11. Quality information

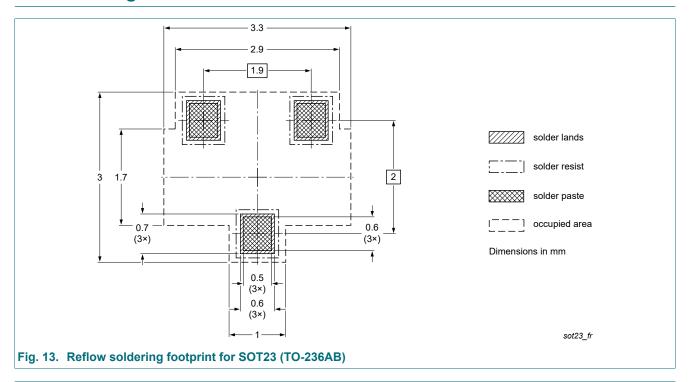
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

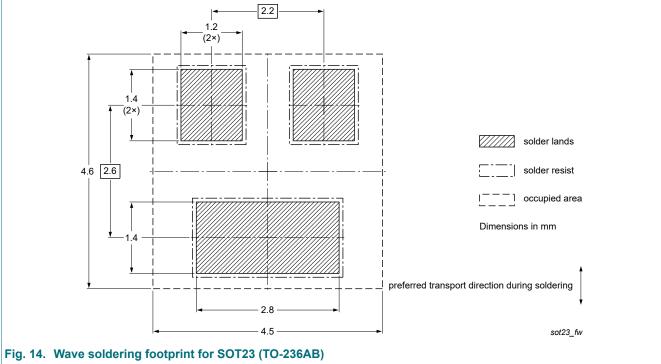
12. Package outline



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13. Soldering





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14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC806_SER v.2	20191105	Product data sheet	-	BC806_SER v.1
Modifications:	Product status char	nged		
BC806_SER v.1	20190909	Preliminary data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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